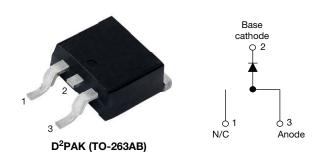


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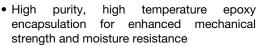
High Performance Schottky Rectifier, 15 A



| PRIMARY CHARACTERISTICS | | | | | | | |
|----------------------------------|-------------------------------|--|--|--|--|--|--|
| I _{F(AV)} | 15 A | | | | | | |
| V _R | 35 V, 40 V, 45 V | | | | | | |
| V _F at I _F | 0.50 V | | | | | | |
| I _{RM} typ. | 70 mA at 125 °C | | | | | | |
| T _J max. | 150 °C | | | | | | |
| E _{AS} | 16 mJ | | | | | | |
| Package | D ² PAK (TO-263AB) | | | | | | |
| Circuit configuration | Single | | | | | | |

FEATURES

- 150 °C T_J operation
- Very low forward voltage drop
- High frequency operation





- Guard ring for enhanced ruggedness and long term reliability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C
- Designed and qualified according to JEDEC®-JESD 47
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

DESCRIPTION

The VS-12TQ...S-M3 Schottky rectifier series has been optimized for very low forward voltage drop, with moderate leakage. The proprietary barrier technology allows for reliable operation up to 150 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

| MAJOR RATINGS AND CHARACTERISTICS | | | | | | | | |
|-----------------------------------|--|-------------|----|--|--|--|--|--|
| SYMBOL CHARACTERISTICS VALUES | | | | | | | | |
| I _{F(AV)} | Rectangular waveform | 15 | Α | | | | | |
| V _{RRM} | Range | 35 to 45 | V | | | | | |
| I _{FSM} | $t_p = 5 \mu s sine$ | 990 | Α | | | | | |
| V _F | 15 A _{pk} , T _J = 125 °C | 0.50 | V | | | | | |
| TJ | Range | -55 to +150 | °C | | | | | |

| VOLTAGE RATINGS | | | | | | | | |
|--------------------------------------|------------------|----------------|----------------|----------------|-------|--|--|--|
| PARAMETER | SYMBOL | VS-12TQ035S-M3 | VS-12TQ040S-M3 | VS-12TQ045S-M3 | UNITS | | | |
| Maximum DC reverse voltage | V_R | 35 | 40 | 45 | W | | | |
| Maximum working peak reverse voltage | V _{RWM} | 33 | 40 | 45 | V | | | |

| ABSOLUTE MAXIMUM RATINGS | | | | | | | | |
|--|--------------------|---|--|-------|----|--|--|--|
| PARAMETER | SYMBOL | TEST CONDI | VALUES | UNITS | | | | |
| Maximum average forward current See fig. 5 | I _{F(AV)} | 50 % duty cycle at T _C = 120 °C | 15 | Α | | | | |
| Maximum peak one cycle | | 5 μs sine or 3 μs rect. pulse | Following any rated | 990 | А | | | |
| non-repetitive surge current See fig. 7 | I _{FSM} | 10 ms sine or 6 ms rect. pulse | load condition and with rated V _{RRM} applied | 250 | | | | |
| Non-repetitive avalanche energy | E _{AS} | T _J = 25 °C, I _{AS} = 2.4 A, L = 5.5 mH | | 16 | mJ | | | |
| Repetitive avalanche current | I _{AR} | Current decaying linearly to zero in 1 μ s Frequency limited by T_J maximum $V_A = 1.5 \times V_R$ typical | | 2.4 | А | | | |

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| ELECTRICAL SPECIFICATIONS | | | | | | | |
|--|--------------------------------|--|---------------------------------------|-------|----|--|--|
| PARAMETER | SYMBOL | TES | VALUES | UNITS | | | |
| Maximum forward voltage drop See fig. 1 | | 15 A | T _{.1} = 25 °C | 0.56 | | | |
| | V (1) | 30 A | 1J = 25 C | 0.71 | V | | |
| | V _{FM} ⁽¹⁾ | 15 A | T 105 %C | 0.50 | V | | |
| | | 30 A | T _J = 125 °C | 0.64 | ĺ | | |
| | 1 (1) | T _J = 25 °C | V Poted V | 1.75 | 0 | | |
| Maximum reverse leakage current | I _{RM} ⁽¹⁾ | T _J = 125 °C | $V_R = Rated V_R$ | 110 | mA | | |
| Typical reverse leakage current | I _{RM} ⁽¹⁾ | T _J = 125 °C | V _R = Rated V _R | 70 | mA | | |
| Maximum junction capacitance | C _T | V _R = 5 V _{DC} (test signal range 100 kHz to 1 MHz), 25 °C | | 900 | pF | | |
| Typical series inductance | L _S | Measured lead to le | 8.0 | nH | | | |
| Maximum voltage rate of change | dV/dt | Rated V _R | 10 000 | V/µs | | | |

Note

 $^{(1)}\,$ Pulse width < 300 $\mu s,$ duty cycle < 2 %

| THERMAL - MECHANICAL SPECIFICATIONS | | | | | | | | |
|--|---------|-----------------------------------|--|----------------------|------------|--|--|--|
| PARAMETER | | SYMBOL TEST CONDITIONS | | VALUES | UNITS | | | |
| Maximum junction and storage temperature range | | T _J , T _{Stg} | | -55 to +150 | °C | | | |
| Maximum thermal resistance, junction to case | | R _{thJC} | DC operation See fig. 4 | 2.0 | °C/W | | | |
| Typical thermal resistance, case to heatsink | | R _{thCS} | Mounting surface, smooth and greased | 0.50 | C/VV | | | |
| Approximate weight | | | | 2 | g | | | |
| Approximate weight | | | | 0.07 | OZ. | | | |
| Manustina tauana | minimum | | | 6 (5) | kgf · cm | | | |
| Mounting torque maxim | | | | 12 (10) | (lbf · in) | | | |
| Marking device | | | Case style D ² PAK (TO-263AB) | 12TQ 12TQ 12TQ | 044S | | | |

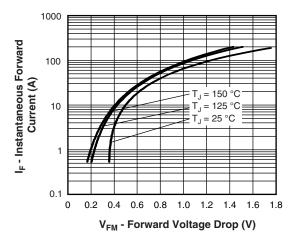


Fig. 1 - Maximum Forward Voltage Drop Characteristics

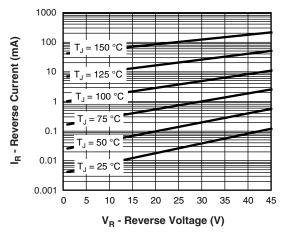


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

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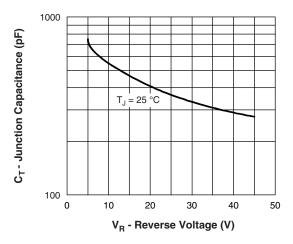


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

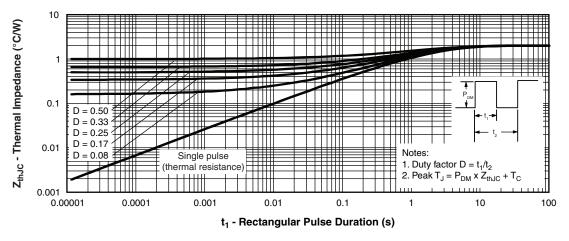


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

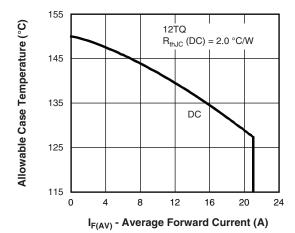


Fig. 5 - Maximum Allowable Case Temperature vs.
Average Forward Current

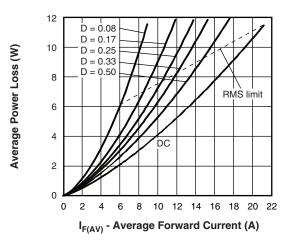


Fig. 6 - Forward Power Loss Characteristics

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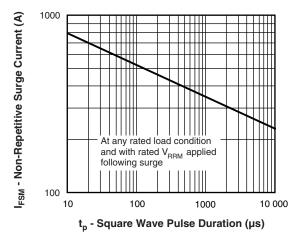


Fig. 7 - Maximum Non-Repetitive Surge Current

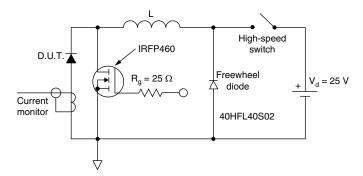
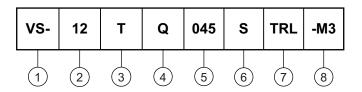


Fig. 8 - Unclamped Inductive Test Circuit

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ORDERING INFORMATION TABLE

Device code



1 - Vishay Semiconductors product

2 - Current rating

3 - Package: T = TO-220

4 - Schottky "Q" series

- Schottky "Q" series 035 = 35 V

7 - • None = tube

• TRL = tape and reel (left oriented)

• TRR = tape and reel (right oriented)

8 - -M3 = halogen-free, RoHS-compliant, and termination lead (Pb)-free

| ORDERING INFORMATION | | | | | | | | | |
|----------------------|------------------|------------------------|--------------------------|--|--|--|--|--|--|
| PREFERRED P/N | QUANTITY PER T/R | MINIMUM ORDER QUANTITY | PACKAGING DESCRIPTION | | | | | | |
| VS-12TQ035S-M3 | 50 | 1000 | Antistatic plastic tubes | | | | | | |
| VS-12TQ035STRR-M3 | 800 | 800 | 13" diameter reel | | | | | | |
| VS-12TQ035STRL-M3 | 800 | 800 | 13" diameter reel | | | | | | |
| VS-12TQ040S-M3 | 50 | 1000 | Antistatic plastic tubes | | | | | | |
| VS-12TQ040STRR-M3 | 800 | 800 | 13" diameter reel | | | | | | |
| VS-12TQ040STRL-M3 | 800 | 800 | 13" diameter reel | | | | | | |
| VS-12TQ045S-M3 | 50 | 1000 | Antistatic plastic tubes | | | | | | |
| VS-12TQ045STRR-M3 | 800 | 800 | 13" diameter reel | | | | | | |
| VS-12TQ045STRL-M3 | 800 | 800 | 13" diameter reel | | | | | | |

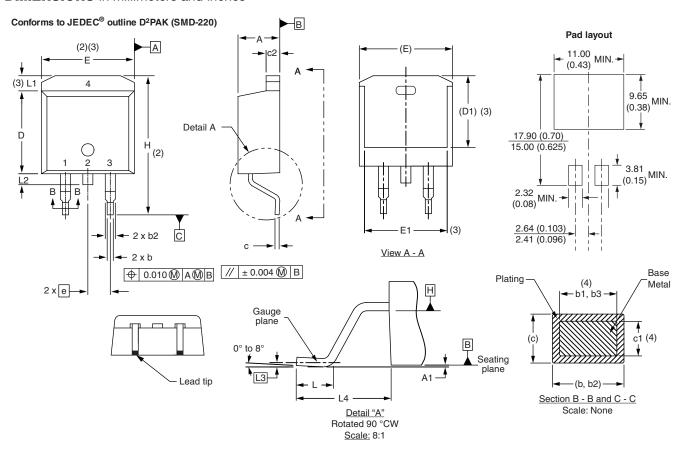
| LINKS TO RELATED DOCUMENTS | | | | | | |
|----------------------------|--------------------------|--|--|--|--|--|
| Dimensions | www.vishay.com/doc?96164 | | | | | |
| Part marking information | www.vishay.com/doc?95444 | | | | | |
| Packaging information | www.vishav.com/doc?96424 | | | | | |



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D²PAK

DIMENSIONS in millimeters and inches



| SYMBOL | MILLIMETERS | | INCHES | | IES NOTES | | SYMBOL | MILLIM | ETERS | INC | HES | NOTES |
|----------|-------------|-------|--------|-------|-----------|-------|---------|--------|-------|-------|-------|-------|
| STIVIBUL | MIN. | MAX. | MIN. | MAX. | NOIES | NOTES | STWIDOL | MIN. | MAX. | MIN. | MAX. | NOTES |
| Α | 4.06 | 4.83 | 0.160 | 0.190 | | | D1 | 6.86 | 8.00 | 0.270 | 0.315 | 3 |
| A1 | 0.00 | 0.254 | 0.000 | 0.010 | | | Е | 9.65 | 10.67 | 0.380 | 0.420 | 2, 3 |
| b | 0.51 | 0.99 | 0.020 | 0.039 | | | E1 | 7.90 | 8.80 | 0.311 | 0.346 | 3 |
| b1 | 0.51 | 0.89 | 0.020 | 0.035 | 4 | | е | 2.54 | BSC | 0.100 |) BSC | |
| b2 | 1.14 | 1.78 | 0.045 | 0.070 | | | Н | 14.61 | 15.88 | 0.575 | 0.625 | |
| b3 | 1.14 | 1.73 | 0.045 | 0.068 | 4 | | L | 1.78 | 2.79 | 0.070 | 0.110 | |
| С | 0.38 | 0.74 | 0.015 | 0.029 | | | L1 | - | 1.65 | - | 0.066 | 3 |
| c1 | 0.38 | 0.58 | 0.015 | 0.023 | 4 | | L2 | 1.27 | 1.78 | 0.050 | 0.070 | |
| c2 | 1.14 | 1.65 | 0.045 | 0.065 | | | L3 | 0.25 | BSC | 0.010 | BSC | |
| D | 8.51 | 9.65 | 0.335 | 0.380 | 2 | | L4 | 4.78 | 5.28 | 0.188 | 0.208 | |

Notes

- (1) Dimensioning and tolerancing per ASME Y14.5 M-1994
- (2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body
- (3) Thermal pad contour optional within dimension E, L1, D1 and E1
- (4) Dimension b1 and c1 apply to base metal only
- (5) Datum A and B to be determined at datum plane H
- (6) Controlling dimension: inch
- (7) Outline conforms to JEDEC® outline TO-263AB



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